NSN 5961-01-343-8878

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-343-8878 **Inclosure Material:** Metal **Overall Length:** Between 0.640 inches and 0.786 inches **Terminal Length:** Between 0.145 inches and 0.210 inches **Overall Height:** Between 0.080 inches and 0.150 inches **Overall Width:** Between 0.275 inches and 0.310 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case and electrostatic sensitive **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 drain to gate voltage all transistor and 60.0 drain to source voltage all transistor and 20.0 gate to source voltage all transistor **Current Rating Per Characteristic:** 225.00 milliamperes drain current all transistor **Power Rating Per Characteristic:** 2.0 watts total power dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: